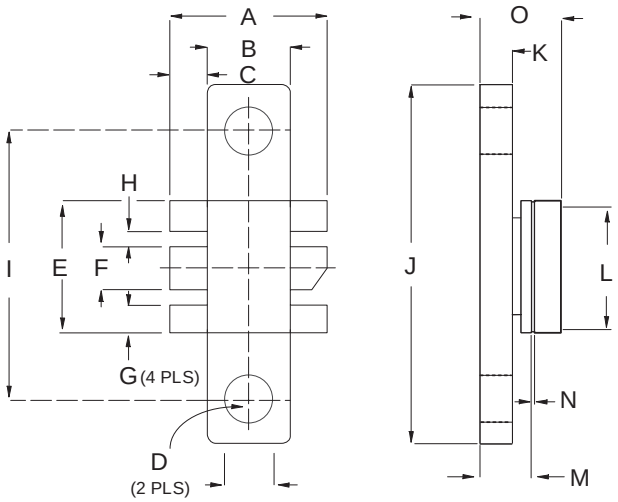
TetraFET

D2294UK

ROHS COMPLIANT METAL GATE RF SILICON FET

MECHANICAL DATA



SOT 171

PIN 1	SOURCE	PIN 2	SOURCE
PIN 3	GATE	PIN 4	DRAIN
PIN 5	SOURCE	PIN 6	SOURCE

DIM	mm	Tol.	Inches	Tol.
A	10.92	0.25	0.430	0.001
B	5.84	0.08	0.230	0.003
C	2.54	0.08	0.100	0.003
D	3.30 dia	0.13	0.130 dia	0.05
E	9.14	0.08	0.360	0.003
F	3.05	0.08	0.120	0.003
G	2.01	0.08	0.079	0.003
H	1.04	0.08	0.041	0.003
I	18.42	0.08	0.725	0.003
J	24.77	0.08	0.975	0.003
K	2.74	0.08	0.108	0.003
L	9.14	0.13	0.360	0.005
M	4.19	0.08	0.165	0.003
N	0.13	0.05	0.005	0.002
O	7.11	MAX	0.280	MAX

GOLD METALLISED MULTI-PURPOSE SILICON DMOS RF FET 15W – 12.5V – 500MHz SINGLE ENDED

FEATURES

- **SIMPLIFIED AMPLIFIER DESIGN**
- **SUITABLE FOR BROAD BAND APPLICATIONS**
- **VERY LOW C_{rss}**
- **SIMPLE BIAS CIRCUITS**
- **LOW NOISE**
- **HIGH GAIN – 11 dB MINIMUM**

APPLICATIONS

- HF/VHF/UHF COMMUNICATIONS from 1 MHz to 1 GHz

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

P_D	Power Dissipation	50W
BV_{DSS}	Drain – Source Breakdown Voltage	40V
BV_{GSS}	Gate – Source Breakdown Voltage	±20V
$I_{D(sat)}$	Drain Current *	12A
T_{stg}	Storage Temperature	–65 to 150°C
T_j	Maximum Operating Junction Temperature	200°C

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Document Number 2810
Issue 2

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ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

Parameter		Test Conditions	Min.	Typ.	Max.	Unit
BV_{DSS}	Drain–Source Breakdown Voltage	V_{GS} = 0 I_D = 10mA	40			V
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 12.5V V_{GS} = 0			1	mA
I_{GSS}	Gate Leakage Current	V_{GS} = 20V V_{DS} = 0			6	µA
$V_{GS(th)}$	Gate Threshold Voltage *	I_D = 10mA V_{DS} = V_{GS}	1		7	V
g_{fs}	Forward Transconductance *	V_{DS} = 10V I_D = 0.6A	1.08			S
G_{PS}	Common Source Power Gain	P_O = 15W	11			dB
η	Drain Efficiency	V_{DS} = 12.5V I_{DQ} = 0.6A	50			%
VSWR	Load Mismatch Tolerance	f = 500MHz	20:1			—
C_{iss}	Input Capacitance	V_{DS} = 0 V_{GS} = –5V f = 1MHz			72	pF
C_{oss}	Output Capacitance	V_{DS} = 12.5V V_{GS} = 0 f = 1MHz			60	pF
C_{rss}	Reverse Transfer Capacitance	V_{DS} = 12.5V V_{GS} = 0 f = 1MHz			6	pF

* Pulse Test: Pulse Duration = 300 µs , Duty Cycle ≤ 2%

HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE.

THERMAL DATA

$R_{THj–case}$	Thermal Resistance Junction – Case	Max.3.5°C / W

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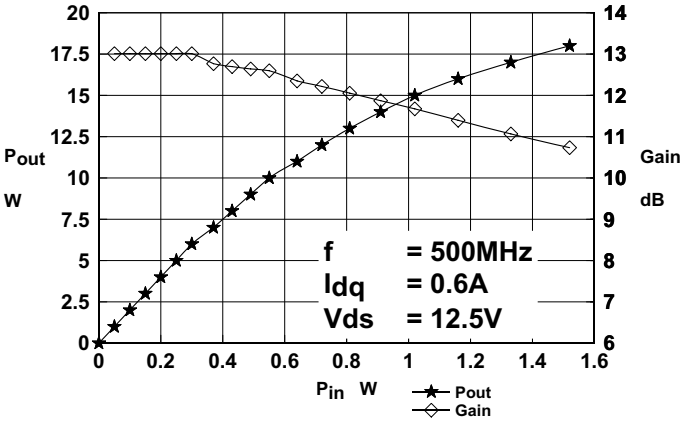

Figure 1
Output power and Gain vs. Input Power

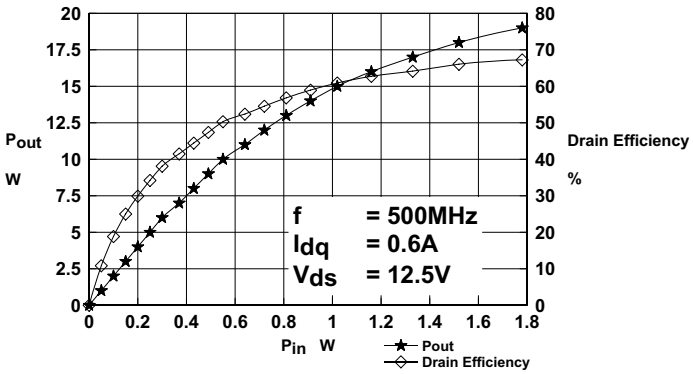

Figure 2
Output power and Efficiency vs. Input Power

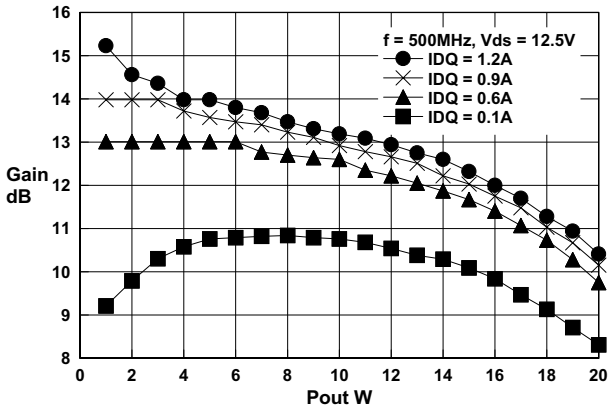

Figure 3
Gain vs Output Power

OPTIMUM SOURCE AND LOAD IMPEDANCE

Frequency MHz	ZL Ω	ZS Ω
500	1.7 + j5.7	3.3+j1.1

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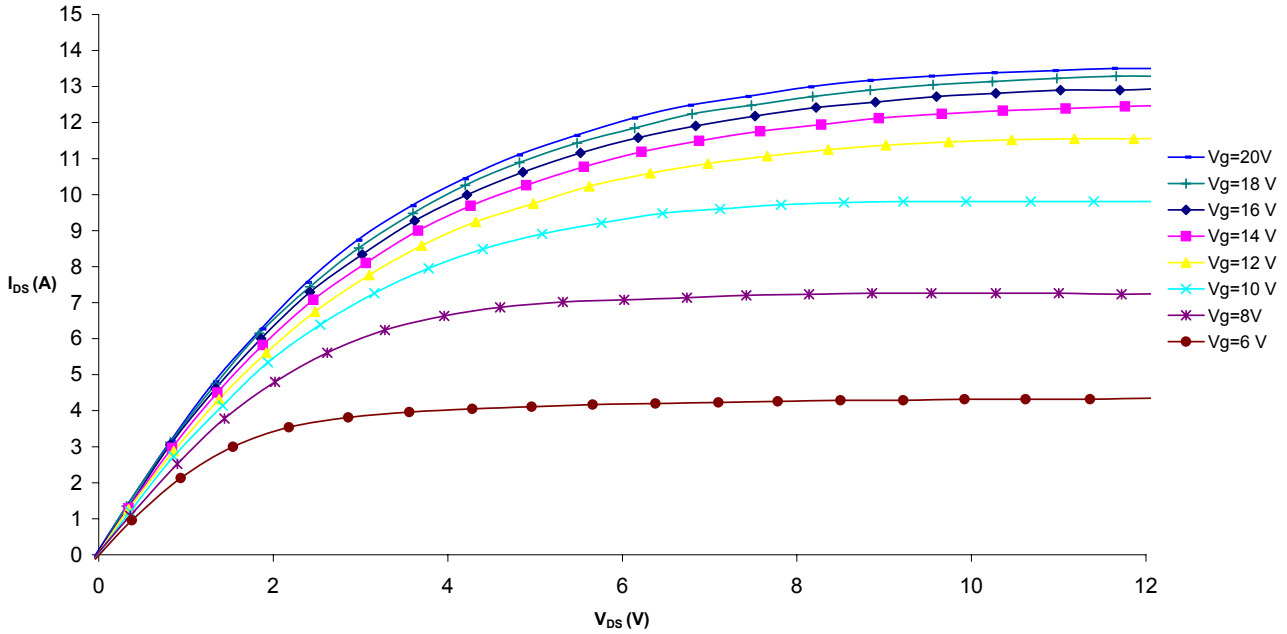

Figure 4 – Typical IV Characteristics.

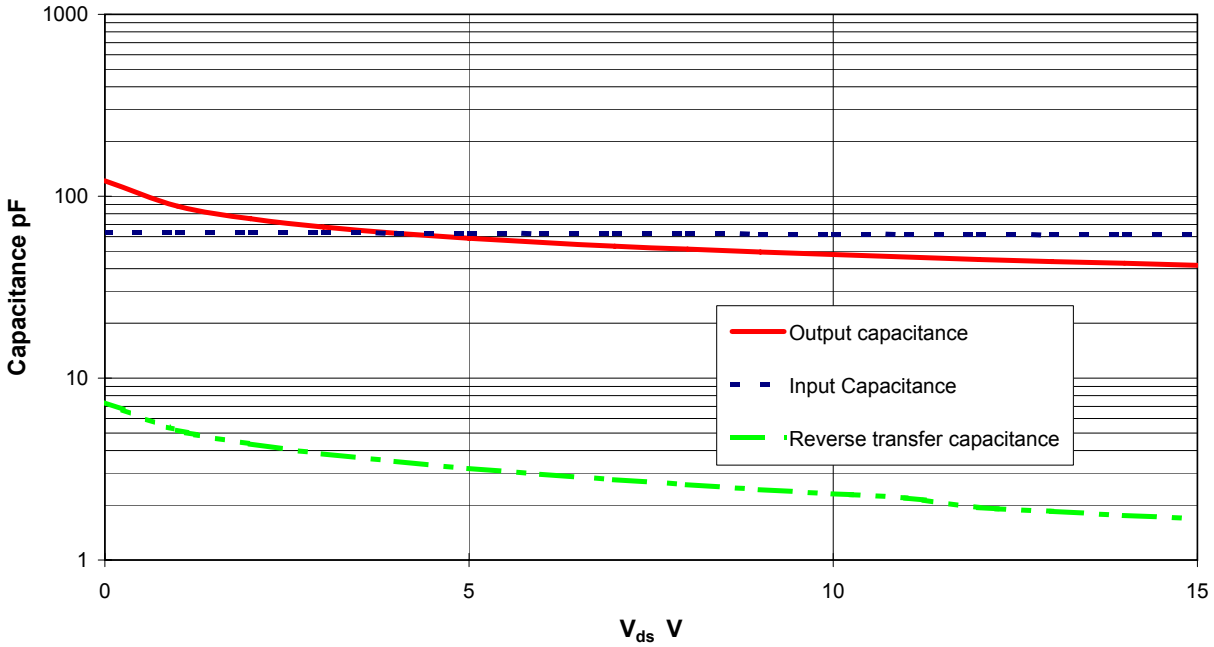

Figure 5 – Typical CV Characteristics.

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Typical S Parameters

! Vds=12.5V, Idq=0.6A
 # MHZ S MA R 50

Freq	S11		S21		S12		S22	
MHz	mag	ang	mag	ang	mag	ang	mag	ang
70	0.73	-137	14.61	92	0.02	2	0.67	-154
100	0.74	-146	10.8	83	0.02	-3	0.69	-159
150	0.76	-154	6.86	69	0.019	-13	0.73	-163
200	0.78	-159	4.8	60	0.017	-18	0.76	-165
250	0.8	-162	3.6	52	0.015	-22	0.79	-167
300	0.82	-165	3	47	0.014	-22	0.82	-168
350	0.84	-167	2.27	38	0.012	-23	0.84	-171
400	0.86	-169	1.92	34	0.01	-23	0.86	-172
450	0.88	-171	1.52	27	0.008	-20	0.88	-174
500	0.89	-173	1.31	24	0.006	-8	0.89	-175
550	0.9	-174	1.09	19	0.006	7	0.91	-177
600	0.92	-175	0.94	12	0.006	17	0.92	-178
650	0.93	-176	0.74	12	0.006	33	0.93	-180
700	0.94	-178	0.65	7	0.007	39	0.94	179
750	0.94	-180	0.53	8	0.007	49	0.94	178
800	0.95	180	0.43	8	0.008	54	0.95	177
850	0.95	180	0.39	14	0.009	65	0.95	176
900	0.96	178	0.37	15	0.011	69	0.96	175
950	0.95	177	0.35	19	0.013	72	0.95	174
1000	0.95	177	0.34	17	0.014	71	0.96	173

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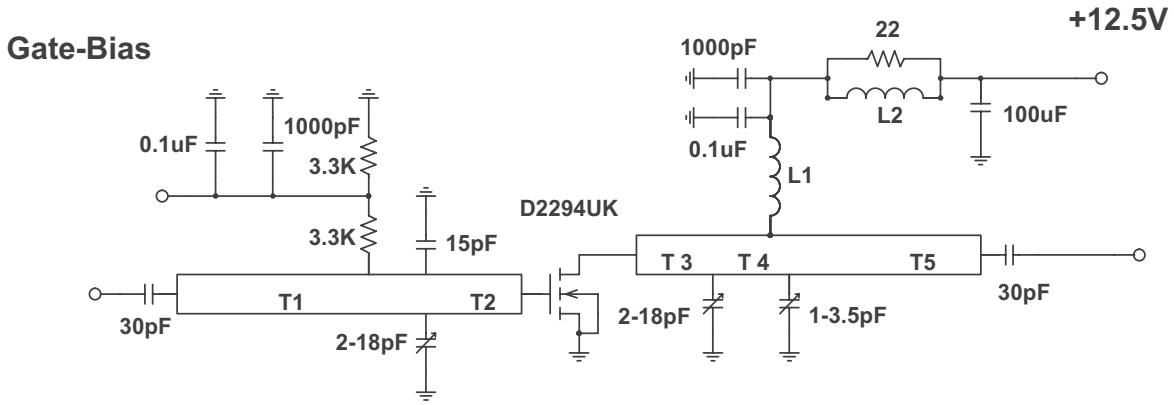

500MHz Test Fixture

Substrate 1.6mm FR4
All microstrip lines W = 2.75mm

T1	47mm
T2	9mm
T3	9mm
T4	13mm
T5	32mm

L1	7 turns 24swg enamelled copper wire, 2mm i.d.
L2	1.5 turns 24swg enamelled copper wire on ferrite core

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